Diode Semiconductor Device - Page 1 of 1



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n closure Material : Blass			
Overall Length: 0.165 inches			
erminal Length:			
.290 inches Overall Diameter:			
0.110 inches			
Nounting Method:			
erminal			
eatures Provided			
lermetically sealed			
Semiconductor Ma	terial:		
Silicon			
	/olts Per Characteristic:		
00.0 reverse volta			
Current Rating Per			
	rd current, average		
	g Tempurature Per Meas	surement Point:	
00.0 degrees celsi			
erminal Type And			
uninsulated wire l	ad		
Shelf Life:			
l/a			
Init Of Measure:			
-			
Demilitarization:			
10			
iig:			
110a0			